MATERIALS CHEMISTRY





FRONTIERS

RESEARCH ARTICLE

View Article Online



Cite this: Mater. Chem. Front., 2022, 6, 748

A meta-linkage strategy towards high-performance hosts for efficient blue thermally activated delayed fluorescence OLEDs†

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The development of high-performance host materials for blue thermally activated delayed fluorescence (TADF) emitters is crucial for realizing efficient blue organic light-emitting diodes (OLEDs). Herein, two star-shaped host materials, tris(3-(diphenylphosphanyl oxide)phenyl)phosphane oxide (m4PO) and tris(3-(carbazole)phenyl)phosphane oxide (m3CzPO), containing a triphenylphosphine oxide (TPPO) core and three meta-substituted diphenylphosphine oxide or carbazolyl groups, are designed and synthesized. The comparative study reveals that the meta-linkage strategy significantly improves the performances of the hosts. The two hosts show superhigh triplet energies of over 3.1 eV, along with high thermal stability, good carrier-transporting capability, and high film quality, which establish the basis for being potentially ideal hosts for blue TADF emitters. Based on a conventional blue TADF emitter bis[4-(9,9-dimethyl-9,10-dihydroacridine)phenyl]sulfone (DMAC-DPS), the blue TADF-OLEDs realize high performances with maximum external quantum efficiencies (EQEs) beyond 20%, maximum power efficiencies (PEs) over 40 lm W^{-1} , a low turn-on voltage of 2.8 V, and a high luminance of up to 5170 nits.

Received 27th December 2021 Accepted 25th January 2022

DOI: 10.1039/d1qm01660a

rsc.li/frontiers-materials

Introduction

Phosphorescent and thermally activated delayed fluorescence (TADF) emitters have attracted extensive research attention as they can achieve a theoretical internal quantum efficiency (IQE) of unity in organic light-emitting diodes (OLEDs) by utilizing both singlet and triplet excitons for light emission. 1-5 To suppress exciton annihilation and concentration quenching in emitting layers, generally, these triplet-excited-state-involved emitters have to be doped into suitable host materials.⁶⁻¹¹ The triplet energy of the host must be higher than that of the emitter to ensure efficient exothermic energy transfer from the host to

the guest molecule and to confine the triplet excitons within the emitting layers. 12-14 In the case of blue emitters, the lowest triplet state (T₁) energy level of the host should be at least 2.9 eV. 15-17 To obtain high triplet energy for a host material, the molecular conjugation must be restricted, and also, the formation of intermolecular excitation such as excimers should be avoided. 9,18,19 These requirements make the design of host materials for triplet-excited-state-involved blue emitters particularly challenging since lowering the conjugation and reducing intermolecular interactions may negatively affect the charge transport properties, which in turn results in inferior device performance.

Much effort has been made to design host materials with high triplet energy and desired charge transport properties for blue emitters. 20-28 However, host materials with a T1 energy of over 3.0 eV, which are highly desired to construct deep-blue OLEDs, are still rare.²⁹ The common hosts include hole-transport-type (p-type) hosts, electron-transport-type (n-type) hosts and bipolar transport hosts. The carbazole-derived groups, which possess rigid molecular structures and good hole-transporting abilities, are popular as the building blocks for p-type and bipolar host materials.30-32 However, the T1 energy level of the carbazolebased host material is usually confined by the conjugation length of carbazole fragments and the formation of excimers from adjacent carbazole units in solid states. Owing to the high T₁ energies and appropriate electron-transporting ability,

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 $[\]dagger$ Electronic supplementary information (ESI) available. CCDC 2117193. For ESI and crystallographic data in CIF or other electronic format see DOI: 10.1039/ d1qm01660a

phosphine oxide derivatives were applied successfully to construct n-type and bipolar host materials for blue OLEDs. 32-40 Furthermore, the linkage mode of the functional groups, which influence the molecular configuration and molecular packing, is equally important in determining the properties of the host materials. 41-43 The influence of positional isomerism on electronic decoupling and the steric hindrance has been widely investigated. 44,45 Para-linkage generally allows planarization, which results in extended π -conjugation and low triplet energy.³⁰ Compared with the para-linkage, the meta-linkage leads to a lower degree of π -conjugation since the metapositions are known to reveal the lower electron densities. 43,46,47 Moreover, the *meta*-linkage could lead to a more twisted molecular configuration and increased steric hindrance which are conducive to inhibiting the formation of excimers. 48,49 Many host materials have been designed using meta-linking mode for high-performance blue and white OLEDs. 24,43-47

Research Article

In this work, we designed two star-shaped host materials, namely tris(3-(diphenylphosphanyl oxide)phenyl)phosphane oxide (m4PO) and tris(3-(carbazole)phenyl)phosphane oxide (m3CzPO), based on a triphenylphosphine oxide (TPPO) scaffold, and three meta-substituted phenylphosphine oxide or carbazole fragments (Fig. 1). Tris(4-(diphenylphosphanyl oxide)phenyl)phosphane oxide (p4PO) containing para-substituted phenylphosphine

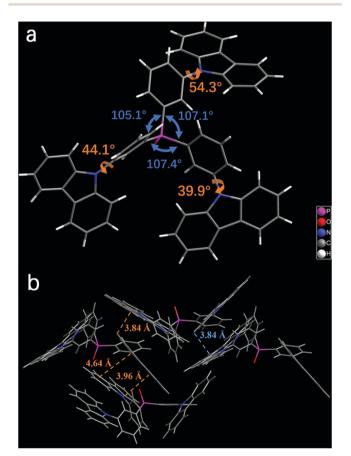


Fig. 1 (a) Crystal structure, and (b) single-crystal packing diagram of m3CzPO

oxide units was synthesized as a reference compound for comparative study. m4PO and m3CzPO show high thermal stability, effective carrier transporting capability, and very high triplet energies of 3.18 eV and 3.10 eV, respectively, which ensures that they are suitable hosts for blue TADF emitters. The corresponding bis[4-(9,9-dimethyl-9,10-dihydroacridine)phenyl] sulfone (DMAC-DPS)-based blue TADF-OLEDs achieved high performance with the maximum external quantum efficiency (EQE) of over 20%, low turn-on voltage at ca 2.8 V, and a high luminance of up to 5170 nits. The result turned out better than that of the reference device based on the host p4PO and is comparable with the high-performance DMAC-DPS-based devices reported (summarized in Table S5, ESI†).

Results and discussion

Synthesis and characterization

The synthetic routes of m4PO, m3CzPO, and p4PO are outlined in Scheme 1. The details are described in the ESI.† The materials were fully purified by column chromatography and then by temperature-gradient vacuum sublimation, and the structures were characterized by mass spectrometry, elemental analysis, NMR spectroscopy. Single crystals of m3CzPO were obtained by diffusion of n-hexane into its CH₂Cl₂ solution. However, we have failed in our deliberate attempts to crystallize the phosphine oxide host m4PO. Single-crystal X-ray diffraction analysis for m3CzPO was performed to investigate the molecular conformation and packing modes (Fig. 1), which would have a significant influence on the photophysical properties. As shown in the Fig. 1, m3CzPO takes a quasi-symmetric and highly twisted molecular configuration. The central TPPO scaffold adopts a pyramidal geometry with three C-P-C angles at 105.1°, 107.1°, and 107.4°, respectively. The meta-substituted carbazole moieties are twisted against the phenyl planes of the TPPO scaffold, with dihedral angles of 44.0°, 53.3°, and 39.9°, respectively. The single crystal packing diagram suggests that the highly twisted molecules of m3CzPO stack into loosely packed aggregates with

Scheme 1 Synthetic routes of the investigated compounds.

intermolecular distances of at least 3.84 Å, indicating no obvious intermolecular interactions. The twisted molecular configuration and the lack of intermolecular contact prevent this host material from forming excimers and exciplexes, and thus maintain high triplet energy in the solid states.

Thermal, morphological, and electrochemical properties

The thermal properties of these host materials were investigated using thermal gravimetric analysis (TGA) and differential scanning calorimetry (DSC) measurements under a nitrogen atmosphere, and the obtained results are summarized in Table 1 and the ESI† (Fig. S1). m4PO and m3CzPO display excellent thermal stabilities with decomposition temperatures (T_d , corresponding to 5% weight loss) of 497 $^{\circ}$ C and 533 $^{\circ}$ C, and glass transition temperatures (T_{g}) of 78 $^{\circ}$ C and 148 $^{\circ}$ C, respectively, which are higher than those of the reference compound **p4PO** ($T_d = 492$ °C, T_g not observed). Obviously, either adopting meta-linkage or incorporating rigid carbazole groups could improve thermal stability. The atomic force microscopy (AFM) images of vacuum-deposited neat films of m4PO and m3CzPO show uniform and smooth surfaces (Fig. S2, ESI†) with a root-mean-square (RMS) roughness of 0.413 nm and 0.465 nm, indicating the good film-forming properties of these compounds as hosts. In comparison, the neat film of p4PO presents a slightly rougher surface with an R_{RMS} value of 0.544 nm. The electrochemical properties of these compounds were examined by performing cyclic voltammetry (CV) in dichloromethane solutions, as shown in Fig. 2. The highest occupied molecular orbital (HOMO) levels of m4PO and m3CzPO were determined from their oxidation potentials^{50,51} to be -6.39 eV and -5.97 eV, respectively. Compared with **m4PO**, **m3CzPO** exhibits a much shallower HOMO level owing to the replacement of the electron-deficient diphenylphosphine oxide units with the electron-donating carbazole units. The lowest unoccupied molecular orbital (LUMO) levels of m4PO and m3CzPO are −2.54 eV and -2.51 eV, respectively, evaluated from the reduction potentials. The energy levels of frontier orbitals rationalize the difference in the inherent carrier transporting capability of these compounds and the luminance of the device hosted by them.

Theoretical simulations

The frontier molecular orbitals and electronic states of m4PO and m3CzPO have been investigated by density functional theory (DFT) and time-dependent DFT (TD-DFT) calculations at the PBE/6-311G(d,p) level. 52 The ground-state molecular geometries of both compounds were highly twisted after optimization. The DFT calculation results show that the HOMO

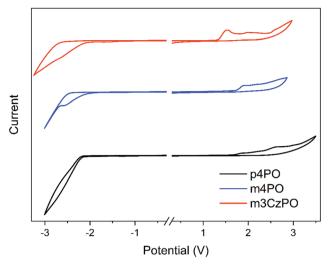


Fig. 2 Cyclic voltammogram of p4PO, m4PO and m3CzPO measured in CH_2Cl_2 at 300 K (scanning rate: 100 mV s⁻¹).

and the LUMO of m4PO are distributed mostly over one of the peripheral diphenylphosphine oxide groups and the central TPPO unit, respectively (Fig. 3). The small HOMO-LUMO overlaps are uncommon for unipolar molecules containing only P=O units, which is attributed to the highly twisted geometry. For the hybrid host m3CzPO, as expected, the LUMO is predominantly located on the central TPPO unit, while the HOMO is largely distributed over the carbazole groups and to a lesser extent over the phenyl rings of the central TPPO unit (Fig. 3). The spatially well-separated frontier orbitals indicate its potential of ambipolar characteristics. m3CzPO shows a LUMO level close to that of m4PO, while the HOMO level of m3CzPO is much shallower than that of m4PO, which is in accordance with the CV results discussed above. As revealed by TD-DFT calculations (Fig. 3 and Fig. S13, Table S3, ESI†), the primary contribution of the lowest singlet excited state (S1) of each compound involves the charge transfer (CT) transition from HOMO to LUMO whereas, the T₁ states of both compounds don't show predominant CT characteristics: the T₁ of m3CzPO is a predominant locally excited (3LE) state, and that of **m4PO** is a hybrid state of 3CT and 3LE.

Photophysical properties

The absorption and photoluminescence (PL) spectra of p4PO, m4PO, m3CzPO, and the typical blue TADF emitter DMAC-DPS in dilute dichloromethane are shown in Fig. 4a and Fig. S11 (ESI†). The UV absorption edge of m4PO is around 286 nm,

Table 1 Summary of properties of p4PO, m4PO and m3CzPO

| Compound | $\lambda_{\mathrm{PL}}{}^{a}\left[\mathrm{nm}\right]$ | $HOMO^b \left[eV\right]$ | $LUMO^b$ [eV] | S_1^c [eV] | T_1^d [eV] | $T_{\rm g}/T_{ m d}$ [°C] | $\mu_{\rm h}/\mu_{\rm e}^{\ e} \left[\times 10^{-6} \ {\rm cm}^2 \ {\rm V}^{-1} \ {\rm s}^{-1} \right]$ |
|----------|---|--------------------------|---------------|--------------|--------------|---------------------------|--|
| p4PO | 370, 420 | -6.25 | -2.45 | 4.08 | 2.95 | /492 | 1.43/6.62 |
| m4PO | 292, 364 | -6.39 | -2.54 | 4.18 | 3.18 | 78/497 | 3.02/11.6 |
| m3CzPO | 396 | -5.97 | -2.51 | 3.87 | 3.10 | 148/533 | 13.4/4.23 |

^a Measured in CH₂Cl₂ (10⁻⁶ mol L⁻¹). ^b Calculated according to the CV measurements. ^c Estimated from the onsets of the time-resolved fluorescence spectra taken at 77 K. ^d Estimated from the onsets of the time-resolved phosphorescence spectra taken at 77 K. ^e Calculated by the SCLC method using the current density-voltage curves of single-carrier devices.

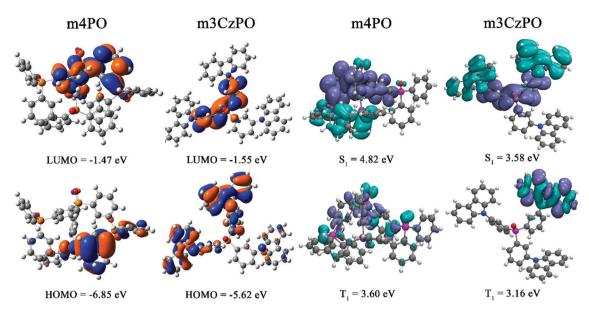


Fig. 3 Left: Frontier molecular orbital distributions, and right: energy-levels and electron-density distribution of the excited states of m4PO and m3CzPO (the purple area denotes an increase in charge density, while the blue area denotes a decrease in charge density).

which is slightly blue-shifted from that of p4PO (291 nm), owing to the weaker conjugation of the meta-linked host

(m4PO) compared with that of its para-linked counterpart (p4PO). By contrast, the hybrid host m3CzPO shows a

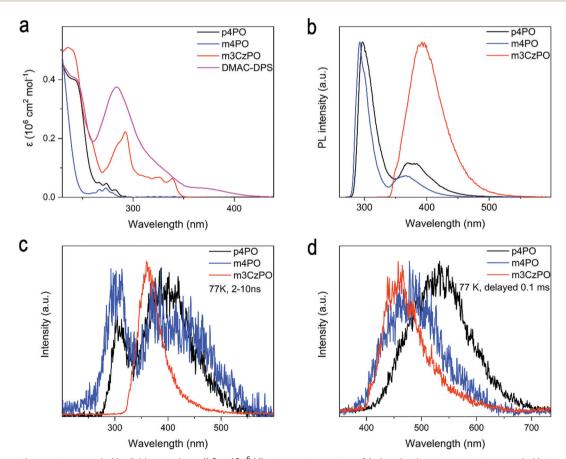


Fig. 4 (a) Absorption spectra recorded in dichloromethane (1.0×10^{-6} M) at room temperature; (b) photoluminescence spectra recorded in transient PL decay of **p4PO**, **m4PO** and **m3CzPO** in dichloromethane $(1.0 \times 10^{-6} \text{ M})$ at room temperature; (c) time-resolved fluorescence spectra (2-10 ns) in dilute 2methyltetrahydrofuran (1.0 \times 10⁻⁶ M) at 77 K; and (d) time-resolved phosphorescence spectra (delayed 0.1 ms) in 2-methyltetrahydrofuran (1.0 \times 10⁻⁶ M) at 77 K.

significantly redshifted absorption edge (348 nm). The absorption bands of m3CzPO at 270-350 nm should probably originate from the π - π * and n- π * transitions of carbazole units. Both PL spectra of p4PO and m4PO in dilute dichloromethane recorded at 298 K comprise dual bands with similar profiles (Fig. 4b). The dual bands of the **m4PO** peak at 292 nm and 364 nm, which are slightly blue-shifted relative to those of p4PO (297 nm and 370 nm), respectively. Emission lifetimes of the low-energy band m4PO and p4PO were measured as 3.84 ns and 1.29 ns, respectively (Fig. S8, ESI†). Therefore, the two-band emission of the two phosphine oxide hosts could be attributed to the radiative transition from the S₁ state which possesses hybrid locally excited (LE) and charge transfer (CT) characteristics. In comparison, the hybrid host m3CzPO exhibits a broad and structureless PL spectrum peak at 400 nm in dichloromethane, indicating its significant intramolecular charge transfer (ICT) characteristics. The PL spectra of these hosts exhibited significant spectral overlaps with the absorption spectrum of DMAC-DPS, which satisfies the basic criterion for efficient Förster resonance energy transfer (FRET) from hosts to DMAC-DPS in doped films. To evaluate the energy levels of S₁ and T₁ states, time-resolved fluorescence and phosphorescence spectra (Fig. 4c and d) of these host materials in 2-methyltetrahydrofuran were recorded at 77 K, from which the S₁ and T₁ energies were evaluated to be 4.08 eV and 2.95 eV for p4PO, 4.18 eV and 3.18 eV for m4PO, and 3.87 eV and 3.10 eV for m3CzPO, respectively. As expected, the T₁ energy level of m3CzPO is very close to that of carbazole (3.11 eV, Fig. S7, ESI†), indicating effective π -conjugation disruption between the *meta*-substituted carbazole units and the phosphine oxide unit. Moreover, m4PO shows a much higher T_1 energy level than that of **p4PO**, probably due to the lower π -conjugation induced by the *meta*-linkage. Such high S₁ and T₁ energies of m4PO and m3CzPO could support efficient exothermic singlet and triplet energy transfer to the blue TADF emitters.

While evaluating the feasibility of using these compounds as hosts for blue TADF emitters, DMAC-DPS $(S_1/T_1 \approx 2.90 \text{ eV})^3$ was used as the guest and doped into p4PO, m4PO, and m3CzPO with a doping concentration of 30 wt%, respectively. The three doped films exhibit similar blue emission originated from DMAC-DPS (peaked at 473-475 nm), without emission from the host materials observed (Fig. S9, ESI†). In addition, these doped films show high photoluminescence quantum yields (PLQYs) ranging from 86% to 89%. These behaviors confirm efficient host-dopant energy transfer. However, the 30 wt% DMAC-DPS doped m4PO film and m3CzPO film reveal the shortened delayed fluorescence (DF) lifetimes, which are expectedly beneficial to quenching the suppression in the emitting layer.

OLED characteristics

To experimentally evaluate the intrinsic carrier transporting abilities of these host materials, hole-only and electron-only devices with device structures of ITO/MoO₃ (6 nm)/HOST (100 nm)/MoO₃ (6 nm)/Al (100 nm) and ITO/LiF (1 nm)/HOST (100 nm)/LiF (1 nm)/Al (100 nm) were fabricated, in which MoO₃ and LiF served as hole and electron injecting layers, respectively. It is assumed that only single carriers are injected

and transported in the devices due to the work function of MoO₃ (or LiF) being high (or low) enough to block electron (or hole) injection. The current density versus voltage curves of these single-carrier devices is depicted in Fig. S14 (ESI†). The hole and electron mobilities (μ_h and μ_e) of the investigated materials were determined using the space charge-limited current (SCLC) method (Table 1). Due to the electrondeficient characteristics of the P=O unit, both p4PO and m4PO expectedly reveal predominant electron-transporting properties. **m4PO** displays higher μ_e and μ_h mobilities (μ_e = $1.16 \times 10^{-5} \text{ cm}^2 \text{ V}^{-1} \text{ S}^{-1}$ and $\mu_h = 3.02 \times 10^{-6} \text{ cm}^2 \text{ V}^{-1} \text{ S}^{-1}$) than those of **p4PO** (μ_e = 6.62 \times 10⁻⁶ cm² V⁻¹ S⁻¹ and μ_h = 1.43 \times 10⁻⁶ cm² V⁻¹ S⁻¹), implying enhanced charge-transport capability with meta-linked P=O units. The carbazole/phosphine oxide hybrid host m3CzPO exhibits a much stronger hole transporting ability than those of p4PO and m4PO, with mobility of up to 1.34×10^{-5} cm² V⁻¹ S⁻¹. In addition, **m4PO** and m3CzPO possess a more balanced carrier transporting capability than p4PO.

To investigate and compare the performance of p4PO, m4PO, and m3CzPO as hosts in the blue OLEDs, the devices with configurations of ITO/MoO₃ (6 nm)/NPB (70 nm)/mCP (10 nm)/HOST: DMAC-DPS (30 wt%, 30 nm)/HOST (10 nm)/ BPhen (40 nm)/LiF (1 nm)/Al (100 nm) were prepared, wherein MoO₃, NPB, mCP, DMAC-DPS, BPhen, and LiF were used as the hole-injecting material, hole-transporting material, electronblocking material, blue emitter, electron-transporting material, and electron-injecting material, respectively. The chemical structures and energy levels of the materials used in these devices are illustrated in Fig. 5a and Fig. S12 (ESI†).

The graphic and numerical data of device performance are shown in Fig. 5b-d and Table 2, respectively. All three devices exhibit typical blue electroluminescence (EL) from DMAC-DPS with the spectral peaks at 470-473 nm and the Commission Internationale de l'Eclairage (CIE) coordinates of (0.16, 0.24), indicating efficient host-to-dopant energy transfer and the good confinement of emissive excitons on the blue emitter. Meanwhile, all devices exhibit approximately equal turn-on voltages of around 2.8 V, indicating a low injection barrier for both electrons and holes to enter the emitting layer.

The OLED hosted by **p4PO** shows a maximum EQE of 16.9%, a maximum current efficiency (CE) of 30.8 cd A⁻¹, a maximum power efficiency (PE) of 35.8 lm W⁻¹. In comparison, the **m4PO**hosted and m3CzPO-hosted devices revealed significantly increased efficiencies, with maximum EQEs of 20.5% and 20.7%, CEs of 36.2 cd A^{-1} and 36.6 cd A^{-1} , and PEs of 40.6 lm W^{-1} b and 40.7 lm W⁻¹, respectively. Moreover, the maximum luminances of the m4PO-hosted and m3CzPO-hosted OLEDs reach 3804 and 5170 cd m⁻², which are much higher than that of the **p4PO**hosted device (2780 cd m⁻²). The improved EL efficiencies and luminance could be mainly ascribed to more efficient and balanced carrier transport and exciton confinement of the hosts with the *meta*-linkage strategy.

For further comparison, two conventional p-type hosts, 4,4'bis(N-carbazolyl)-1,1'-biphenyl (CBP) and 3,3'-di(9H-carbazol-9yl)-1,1'-biphenyl (mCBP), were employed to fabricate OLEDs

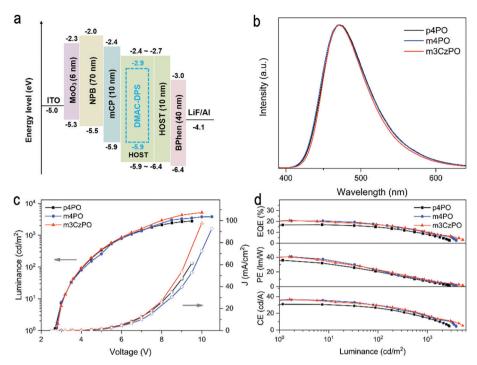


Fig. 5 (a) Energy level diagram of the OLEDs; (b) electroluminescence (EL) spectrum; (c) current density-luminance-voltage (J-V-L) characteristics; and (d) external quantum efficiency (EQE), power efficiency (PE) and current efficiency (CE) versus luminance characteristics

Table 2 EL performance of OLEDs using DMAC-DPS as the emitter, and p4PO, m4PO and m3CzPO as the host matrix

| Host | Emitter | $\lambda_{\mathrm{EL}}{}^{a}\left[\mathrm{nm}\right]$ | $L_{\rm max}^{ b} \left[{\rm cd} \ {\rm m}^{-2} \right]$ | $V^c[V]$ | CE_{max} [cd A^{-1}] | PE_{max} [lm W ⁻¹] | EQE _{max} [%] | CIE^d |
|--------|----------|---|---|----------|---------------------------|----------------------------------|------------------------|------------------|
| p4PO | DMAC-DPS | 470 | 2780 | 2.7 | 30.8 | 35.8 | 16.9 | (0.16, 0.24) |
| m4PO | DMAC-DPS | 473 | 3804 | 2.8 | 36.2 | 40.6 | 20.5 | (0.16, 0.24) |
| m3CzPO | DMAC-DPS | 471 | 5170 | 2.8 | 36.6 | 40.6 | 20.7 | (0.16, 0.24) |

^a EL maximum wavelength at 6 V. ^b The maximum luminance. ^c Turn-on voltage taken at 1 cd m⁻². ^d Value at 500 cd m⁻².

with the same configuration of ITO/MoO₃ (6 nm)/NPB (70 nm)/ mCP (10 nm)/CBP or mCBP: DMAC-DPS (30 wt%, 30 nm)/m4PO (10 nm)/BPhen (40 nm)/LiF (1 nm)/Al (100 nm). As shown in Fig. S22 and Table S4 (ESI†), the device performance of the CBP-hosted device (EQE_{max} of 6.2%) and the mCBP-hosted device (EQE_{max} of 15.8%) are inferior to those of m4POhosted and m3CzPO-hosted devices. This can be attributed to the relatively low triplet energies of CBP ($T_1 = 2.6 \text{ eV}$) and mCBP $(T_1 = 2.9 \text{ eV})^{53}$, which may result in back energy transfer from the dopant (DMAC-DPS, $T_1 = 2.91 \text{ eV}$) to the host.

Conclusions

In summary, two new host materials, m4PO and m3CzPO, have been constructed with a TPPO scaffold and three metasubstituting diphenylphosphine oxide units or carbazole units. The meta-linkage between the diphenylphosphine oxide or carbazole substituents and the TPPO scaffold could bring in the highly twisted molecular conformation, in turn leading to a minimized π conjugation and high T₁ energies of 3.18 eV for m4PO and 3.10 eV for m3CzPO, respectively. Compared with the para-linking

counterpart p4PO, compounds m4PO and m3CzPO exhibit higher T₁ energy levels, improved thermal stability, and enhanced and balanced carrier transporting capability. By using DMAC-DPS as the blue TADF emitter, the multilayer OLEDs hosted by m4PO and m3CzPO achieved maximum EQEs of 20.5% and 20.7%, CE of $36.2 \text{ cd A}^{-1} \text{ and } 36.6 \text{ cd A}^{-1}, \text{ PE of } 40.6 \text{ lm W}^{-1} \text{ and } 40.6 \text{ lm W}^{-1},$ and maximum luminescence of 3804 cd m⁻² and 5170 cd m⁻² respectively, which were significantly increased in contrast to the p4PO-based reference device. This work exemplifies the superiority of the meta-linkage strategy for the development of blue host materials.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

This work was supported by the Strategic Priority Research Program of the Chinese Academy of Sciences (XDB20000000), the Key Research Program of Frontier Science, CAS (QYZDJ-SSW-SLH033), the National Natural Science Foundation of China (52073286, 21805281, 21875252, 21773246, and 21403176), the Natural Science Foundation of Fujian Province (2006L2005, 2019J01125, and 2019J01123), the Fujian Science & Technology Innovation Laboratory for Optoelectronic Information of China (2021ZR132), the Youth Innovation Foundation of Xiamen City (3502Z20206082, and 3502Z20206083), and the Opening Project of PCOSS, Xiamen University (202014).

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